

v05.1211

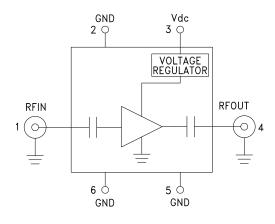


# **Typical Applications**

The HMC-C045 LNA is ideal for:

- Telecom Infrastructure
- Microwave Radio & VSAT
- Military & Space
- Test Instrumentation

## **Functional Diagram**



# LOW NOISE AMPLIFIER MODULE, 1.8 - 4.2 GHz

### **Features**

Noise Figure: 1.2 dB @ 2.4 GHz

Gain: 26 dB OIP3: +26 dBm

P1dB Output Power: +15.5 dBm 50 Ohm Matched Input/Output Hermetically Sealed Module

Field Replaceable SMA Connectors

-55 °C to +85 °C Operating Temperature

# **General Description**

The HMC-C045 is a GaAs MMIC pHEMT Low Noise Amplifier in a miniature, hermetic module which operates between 1.8 and 4.2 GHz. This high dynamic range low noise amplifier module provides 26 dB of gain, sub-2 dB noise figure and up to +26 dBm of output IP3 while operating from a single positive supply between +8V and +15V. The amplifier I/Os are internally matched to 50 Ohms and DC blocked for robust performance. The module features removable coaxial connectors which can be detached to allow direct connection of the I/O pins to a microstrip or coplanar circuit.

# Electrical Specifications, $T_A = +25^{\circ}$ C, Vdc = +12V

Parameter	Min.	Тур.	Max.	Min.	Тур.	Max.	Units
Frequency Range	1.8 - 4.2		2.0 - 3.8			GHz	
Gain	23	26		23	26		dB
Gain Variation Over Temperature		0.03	0.05		0.03	0.05	dB/ °C
Noise Figure		1.2	2.5		1.2	2.0	dB
Input Return Loss		13			13		dB
Output Return Loss		13			13		dB
Output Power for 1 dB Compression (P1dB)	12.5	15.5		12.5	15.5		dBm
Saturated Output Power (Psat)		17.5			17.5		dBm
Output Third Order Intercept (IP3)		26			26		dBm
Supply Current		105	140		105	140	mA

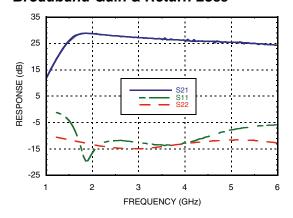


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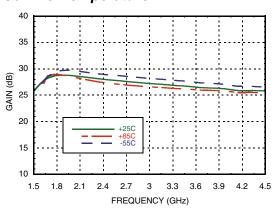


# LOW NOISE AMPLIFIER MODULE, 1.8 - 4.2 GHz

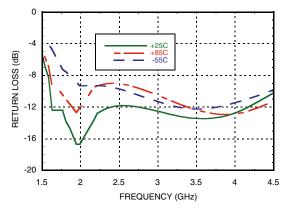
#### **Broadband Gain & Return Loss**



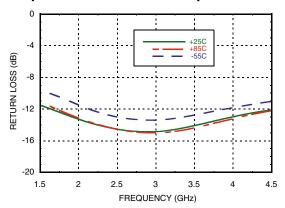
### Gain vs. Temperature



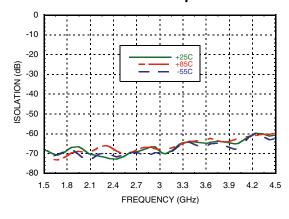
## Input Return Loss vs. Temperature



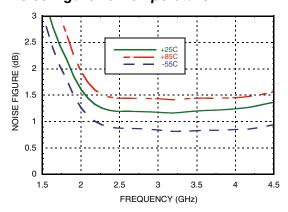
### **Output Return Loss vs. Temperature**



### Reverse Isolation vs. Temperature



### Noise Figure vs. Temperature

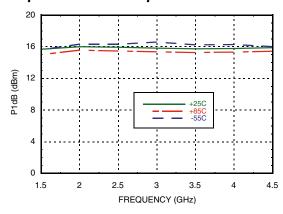




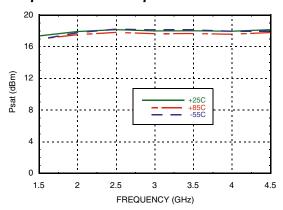


# LOW NOISE AMPLIFIER MODULE, 1.8 - 4.2 GHz

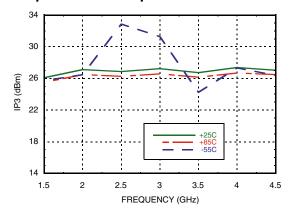
### Output P1dB vs. Temperature



### Output Psat vs. Temperature



## Output IP3 vs. Temperature



# **Absolute Maximum Ratings**

Bias Supply Voltage (Vdc)	+15 Vdc		
RF Input Power (RFIN)	+0 dBm		
Storage Temperature	-65 to +150 °C		
Operating Temperature	-55 to +85 °C		





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# LOW NOISE AMPLIFIER MODULE, 1.8 - 4.2 GHz

## **Pin Descriptions**

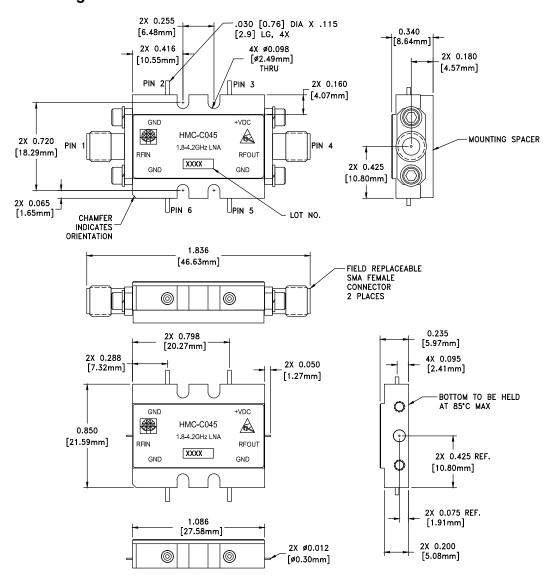
Pin Number	Function	Description	Interface Schematic	
1	RFIN & RF Ground	RF input connector, coaxial female, field replaceable. This pin is AC coupled and matched to 50 Ohms.	RFINO—  -	
2, 5, 6	GND	One of these pins must be connected to power supply ground.	⊖ GND =	
3	Vdc	Power supply voltage for the amplifier.	Vdc O VOLTAGE REGULATOR =	
4	RFOUT & RF Ground	RF output connector, coaxial female, field replaceable. This pin is AC coupled and matched to 50 Ohms.	→ FOUT	





# LOW NOISE AMPLIFIER MODULE, 1.8 - 4.2 GHz

### **Outline Drawing**



VIEW SHOWN WITH CONNECTORS AND MOUNTING SPACER REMOVED

## Package Information

Package Type	C-10	
Package Weight [1]	18.7 gms <sup>[2]</sup>	
Spacer Weight	3.3 gms <sup>[2]</sup>	

[1] Includes the connectors

[2] ±1 gms Tolerance

#### NOTES:

- 1. PACKAGE, LEADS, COVER MATERIAL: KOVAR™
- 2. FINISH: GOLD PLATE OVER NICKEL PLATE
- 3. ALL DIMENSIONS ARE IN INCHES [MILLIMETERS]
- 4. TOLERANCES:
- $4.1 .XX = \pm 0.02$
- $4.2 .XXX = \pm 0.010$
- 5. FIELD REPLACEABLE SMA CONNECTORS







**ANALOG**DEVICES

LOW NOISE AMPLIFIER MODULE, 1.8 - 4.2 GHz

Notes: